

IGBT MODULE (S-Series)

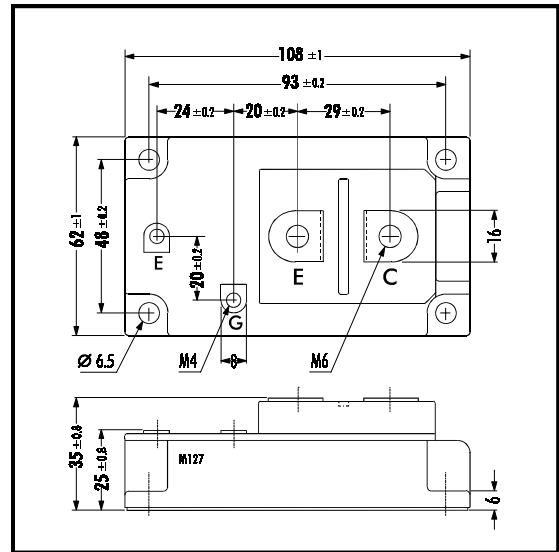
■ Outline Drawing

■ Features

- NPT-Technology
- Square SC SOA at $10 \times I_C$
- High Short Circuit Withstand-Capability
- Small Temperature Dependence of the Turn-Off Switching Loss
- Low Losses And Soft Switching

■ Applications

- High Power Switching
- A.C. Motor Controls
- D.C. Motor Controls
- Uninterruptible Power Supply



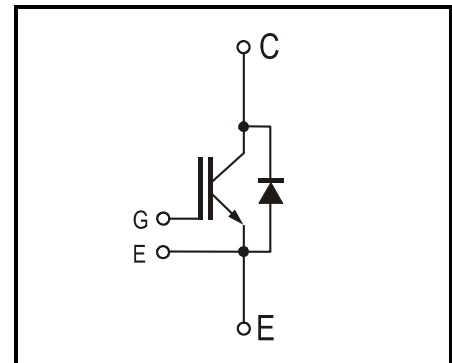
■ Maximum Ratings and Characteristics

• Absolute Maximum Ratings ($T_c=25^\circ\text{C}$)

Items		Symbols	Rated Values	Units
Collector-Emitter Voltage		V_{CES}	1200	V
Gate -Emitter Voltage		V_{GES}	± 20	
Collector Current	Continuous	I_C	400 / 300	A
	1ms	$I_{C\ PULSE}$	800 / 600	
	Continuous	$-I_C$	300	
	1ms	$-I_{C\ PULSE}$	600	
Max. Power Dissipation		P_C	2100	W
Operating Temperature		T_j	+150	$^\circ\text{C}$
Storage Temperature		T_{stg}	-40 ~ +125	
Isolation Voltage *1	A.C. 1min.	V_{is}	2500	V
Screw Torque	Mounting *2		3.5	Nm
	Terminals *2		4.5	
	Terminals *2		1.7	

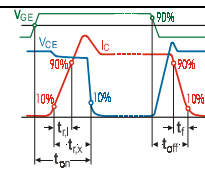
Note: 1*: All Terminals should be connected together when isolation test will be done.
2*: Recommendable Value: Mounting 2.5 ~ 3.5 Nm (M5) or (M6); Terminal 3.5 ~ 4.5 Nm (M6), 1.3 ~ 1.7 Nm (M4)

■ Equivalent Circuit



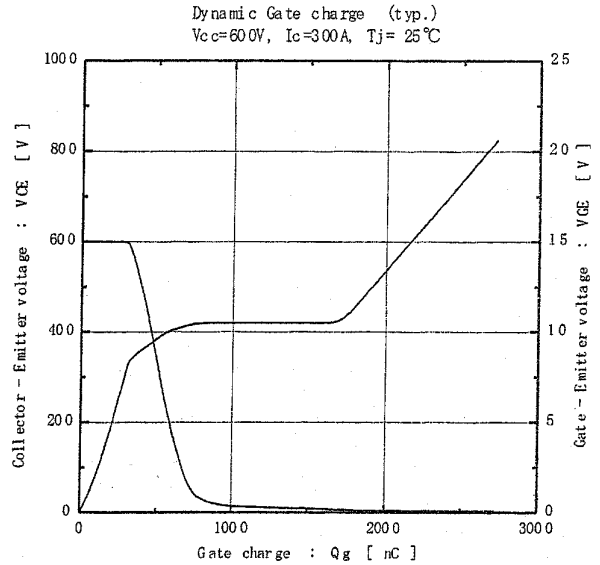
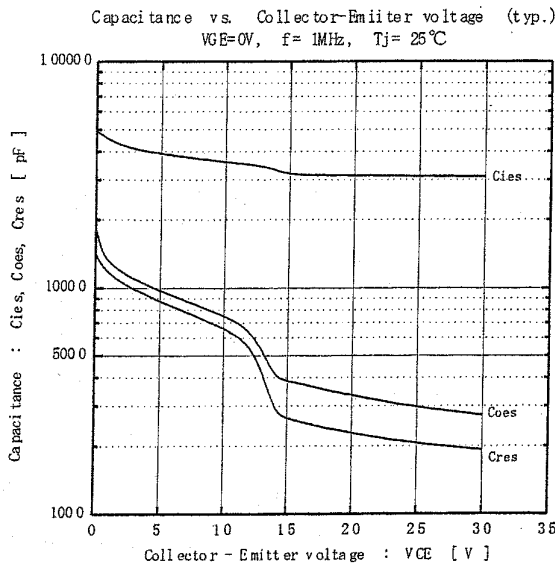
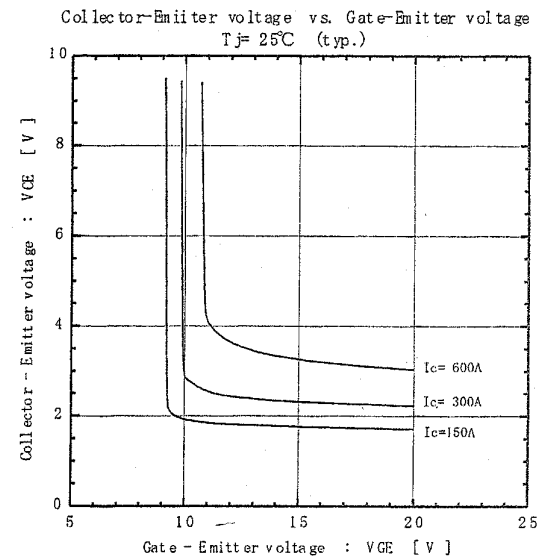
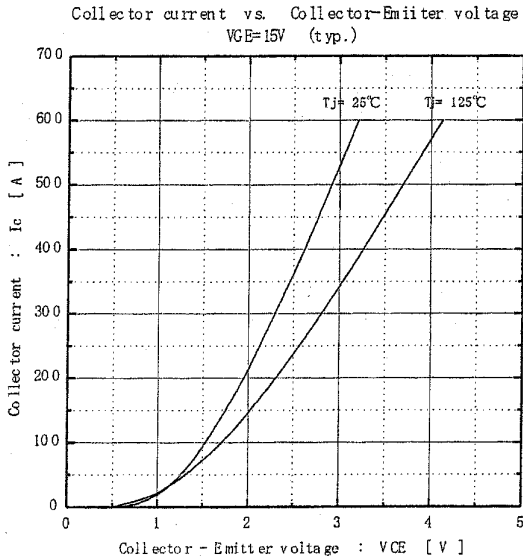
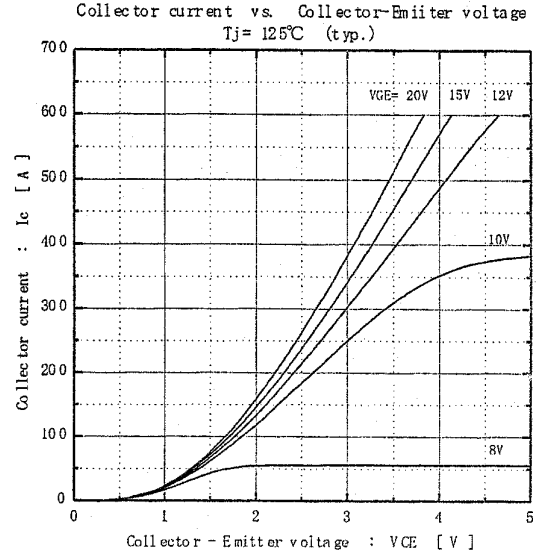
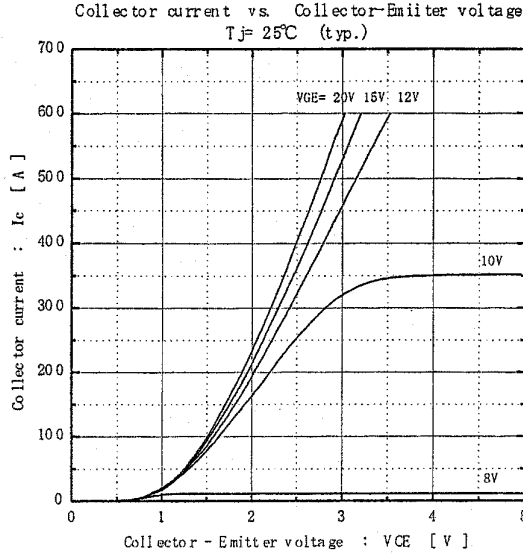
• Electrical Characteristics (at $T_j=25^\circ\text{C}$)

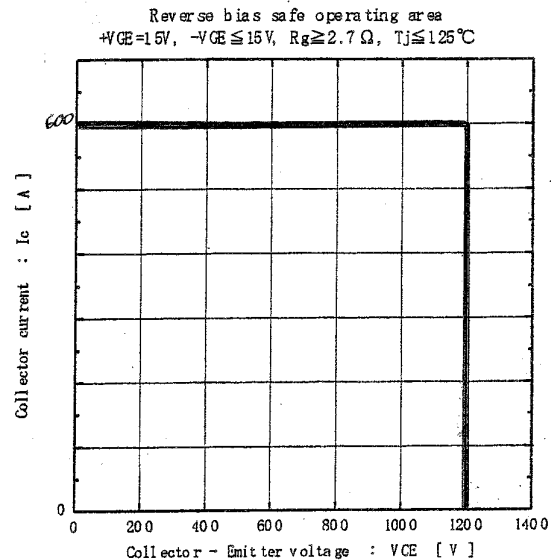
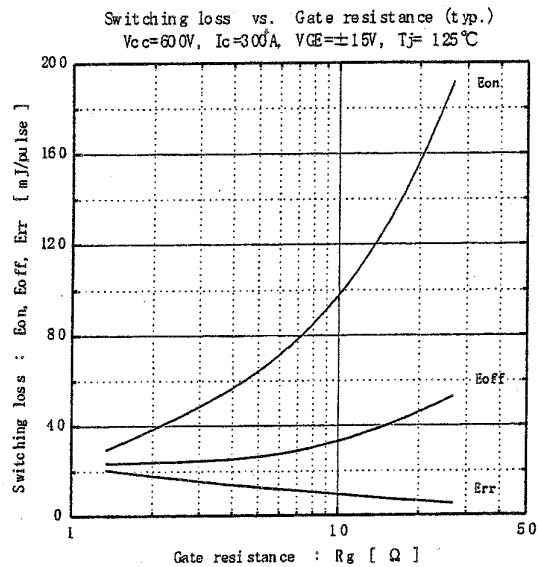
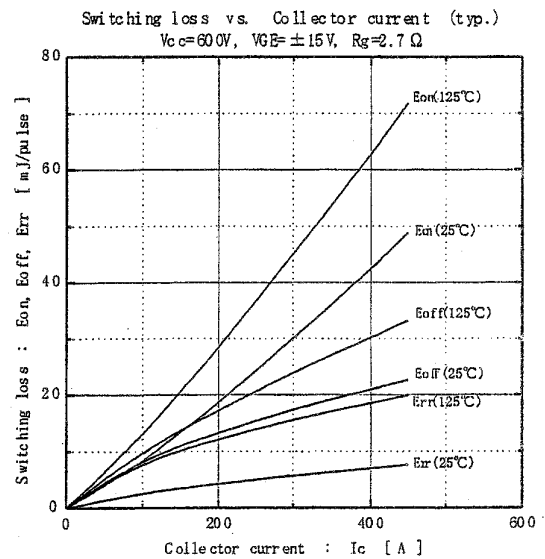
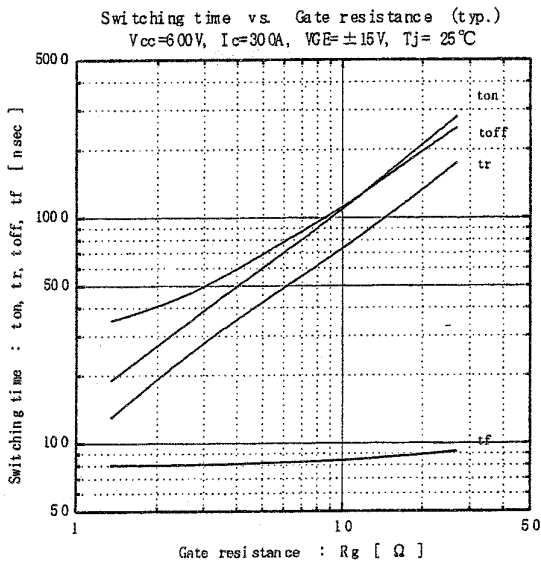
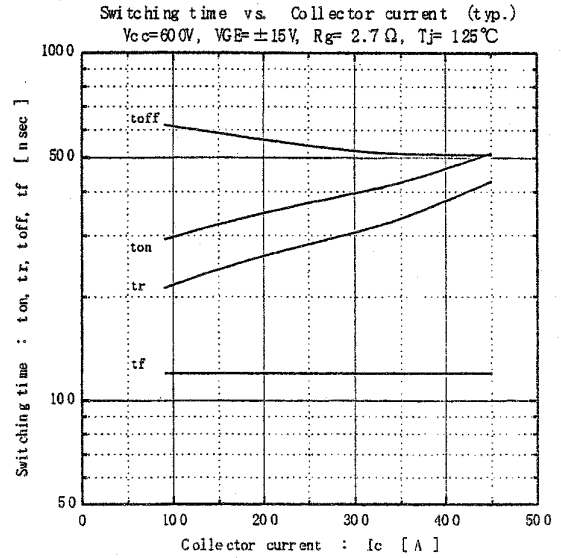
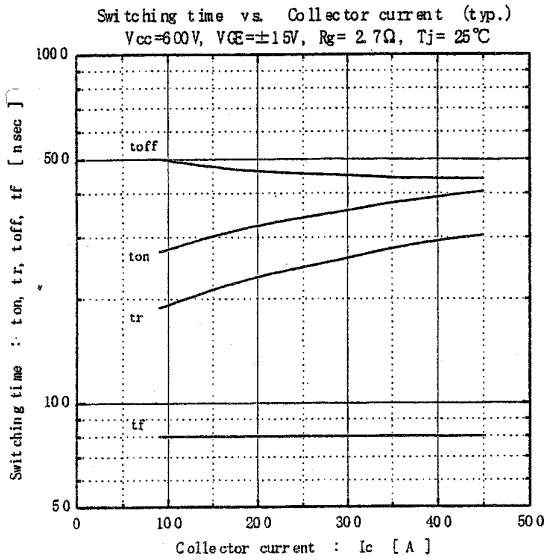
Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Zero Gate Voltage Collector Current	I_{CES}	$V_{GE}=0V$ $V_{CE}=1200V$			4.0	mA
Gate-Emitter Leakage Current	I_{GES}	$V_{CE}=0V$ $V_{GE}=\pm 20V$			800	nA
Gate-Emitter Threshold Voltage	$V_{GE(th)}$	$V_{GE}=20V$ $I_C=300mA$	5.5	7.2	8.5	V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$V_{GE}=15V$ $I_C=300A$		2.3	2.6	
Input Capacitance	C_{ies}	$V_{GE}=0V$		36'000		pF
Output Capacitance	C_{oes}	$V_{CE}=10V$		7'500		
Reverse Transfer Capacitance	C_{res}	$f=1MHz$		6'600		
Turn-on Time	t_{ON}	$V_{CC}=600V$		0.35	1.2	μs
	$t_{r,x}$	$I_C=300A$		0.25	0.6	
	$t_{r,i}$	$V_{GE}=\pm 15V$		0.10		
Turn-off Time	t_{OFF}	$R_G=2.7\Omega$		0.45	1.0	μs
	t_f	Inductive Load		0.08	0.3	
Diode Forward On-Voltage	V_F	$I_F=300A$; $V_{GE}=0V$		2.3	3.0	V
Reverse Recovery Time	t_{rr}	$I_F=300A$		2.0	350	



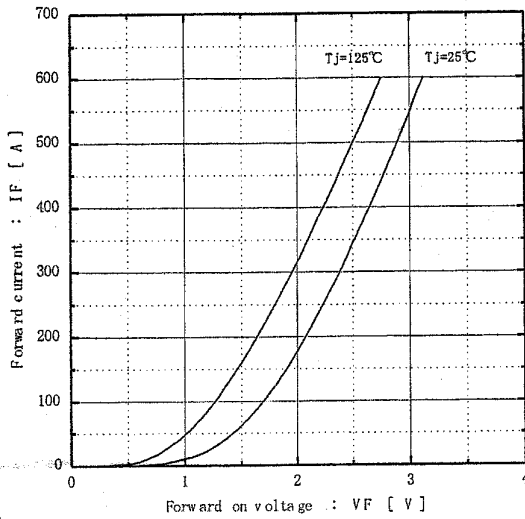
• Thermal Characteristics

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance	$R_{th(j-c)}$	IGBT			0.06	$^\circ\text{C/W}$
	$R_{th(j-e)}$	Diode			0.17	
	$R_{th(c-f)}$	With Thermal Compound		0.0125		

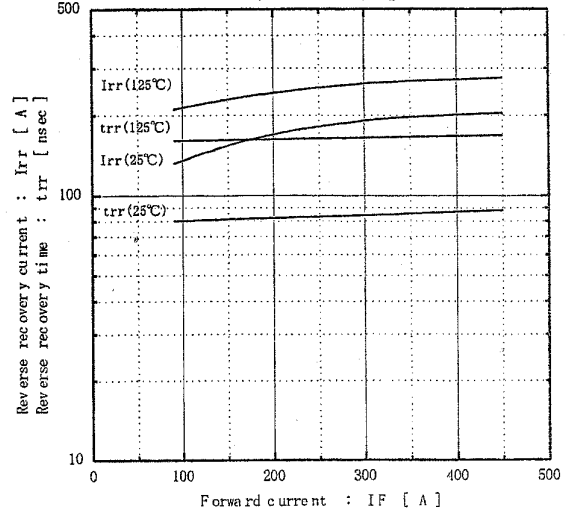




Forward current vs. Forward on voltage (typ.)



Reverse recovery characteristics (typ.)
Vcc=600V, VGE=±15V, Rg=2.7Ω



Transient thermal resistance

